## transistor

# 2SC5398

For Low Frequency Amplify Application Silicon NPN Epitaxial Type Micro

## DESCRIPTION

2SC5398 is a silicon NPN epitaxial type transistor.

It is designed for low frequency voltage amplify application.

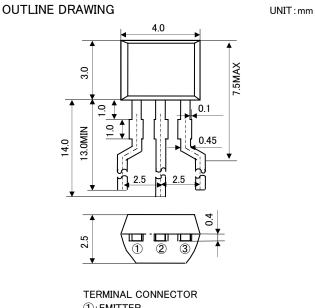
#### FEATURE

·Low collector to emitter saturation voltage

- $V_{CE(sat)} = 0.3V max(@I_{C}=30mA,I_{B}=1.5mA)$
- •Excellent linearity of DC forward current gain
- •Small package for easy mounting

## **APPLICATION**

Small machine low frequency voltage amplify application

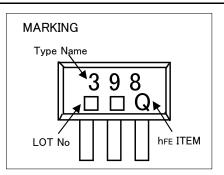


1: EMITTER EIAJ: -2:COLLECTOR 3:BASE

JEDEC: -

### MAXIMUM RATINGS(Ta=25°C)

Symbol	Parameter	Ratings		
Vсво	Collector to Base voltage	50	V	
Vebo	Emitter to Base voltage	6	V	
VCEO	Collector to Emitter voltage	50	V	
Ic	Collector current	100	mA	
Pc	Collector dissipation	450	mW	
Tj	Junction temperature	+150	°C	
Tstg	Storage temperature	-55~+150	°C	



#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

Parameter	Symbol	Test conditions		Limits			
				Min	Тур	Max	Unit
V(BR)CEO	C to E breakdown voltage	$I_{\rm C}$ = 100 $\mu$ A , RBE= $\infty$		50	-	-	V
Ісво	Collector cut off current	V $_{CB}$ = 50V , I $_{E}$ = 0		-	-	0.5	μA
IEBO	Emitter cut off current	V <sub>EB</sub> = 4V , I <sub>C</sub> = 0		-	_	0.5	μA
hFE	DC forward current gain 💥	V $_{CE}$ = 6V , $I_{C}$ = 1mA		120	(※)	560	-
hFE	DC forward current gain	V $_{CE}$ = 6V , $I_{C}$ = 0.1mA		70	_	-	-
VCE(sat)	C to E Saturation voltage	$I_{\rm C}$ =30mA , I $_{\rm B}$ = 1.5mA		-	-	0.3	V
fT	Gain bandwidth product	V <sub>CE</sub> = 6V , I <sub>E</sub> = -10mA		-	200	_	MHz
Cob	Collector output capacitance	V <sub>CB</sub> = 6V , I <sub>E</sub> = 0, f=1MHz	2	-	2.0	-	pF
	E classification at right table.	·					
			Item	Q	R		S
			hFE	120~270	180~	390	270~560

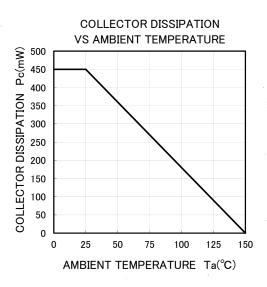
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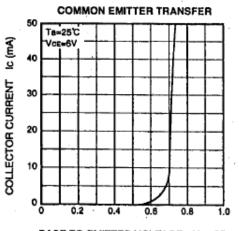
transistor

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#### TYPICAL CHARACTERISTICS





BASE TO EMITTER VOLTAGE VIE (V)

GAIN BAND WIDTH PRODUCT

VS. EMITTER CURRENT

fr (MHz)

GAIN BAND WIDTH PRODUCT

250

200

150

100

50

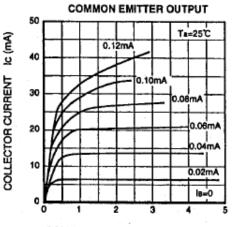
0

-0.1-0.2

-0.5 -1 -2 -5 -10 -20

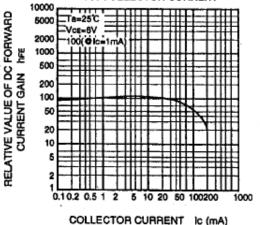
EMITTER CURRENT IE (mA)

Ta=25 C

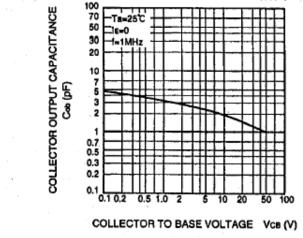


COLLECTOR TO EMITTER VOLTAGE VCE (V)

DC FORWARD CURRENT GAIN VS. COLLECTOR CURRENT



COLLECTOR OUTPUT CAPACITANCE VS. COLLECTOR TO BASE VOLTAGE



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